Virtual Prototyping of a Microwave Fin Line Power Spatial Combiner Amplifier A. Leggieri¹, F. Di Paolo¹ and D. Passi¹ ¹Department of Electronic Engineering, University of Rome "Tor Vergata", Italy

Introduction: This study describes the Virtual Prototyping of a novel X-Band Fin Taper (FT) Spatial Power Combiner (SPC) Amplifier based on rectangular waveguide (WG). Thermal expansion induced by the power dissipation of the active devices, is employed to compute Electric Fields and S-

electromagnetic behavior is in-line with design requirements; but displacement value is incompatible with the GaAs survivability: for such reason, an interface layer is needed between the back of the GaAs active devices and the copper carrier: used materials are CuW

parameters in working conditions.

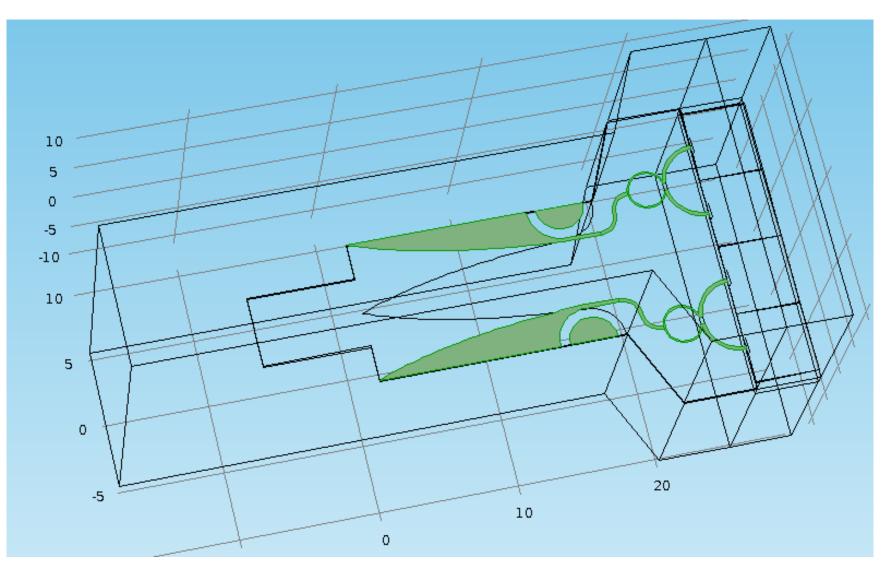


Figure 1. The proposed SPC.

Computational Methods: Thermal Stress (TS) and Electromagnetic (EM) analysis are coupled by Moving Mesh (MM) interface and by storing temperature information.

Electromagnetic behaviour in Working conditions

or CuMo.

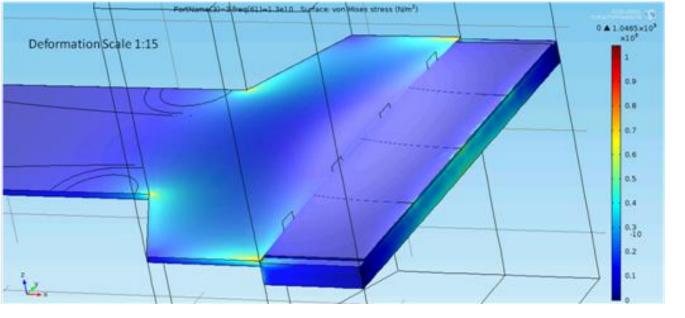


Figure 4. Stress.

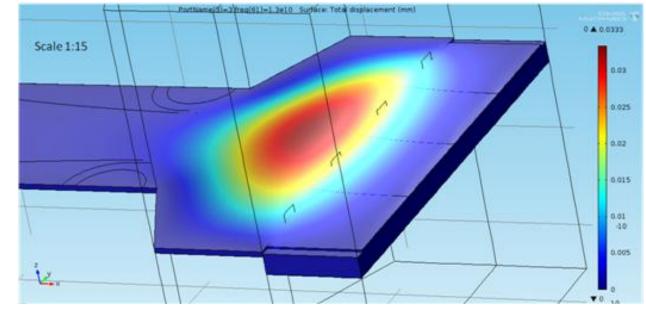


Figure 5. Displacement.

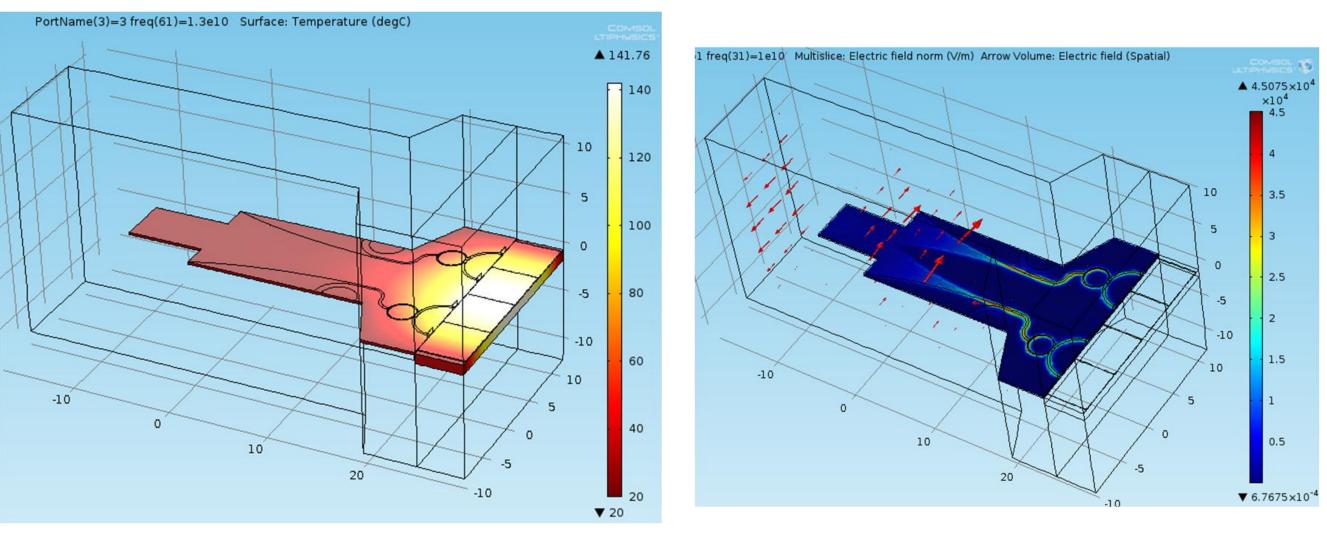
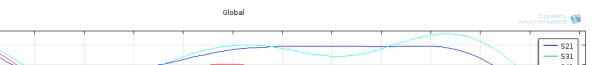


Figure 6. Temperature.

Figure 7. Electric Field.





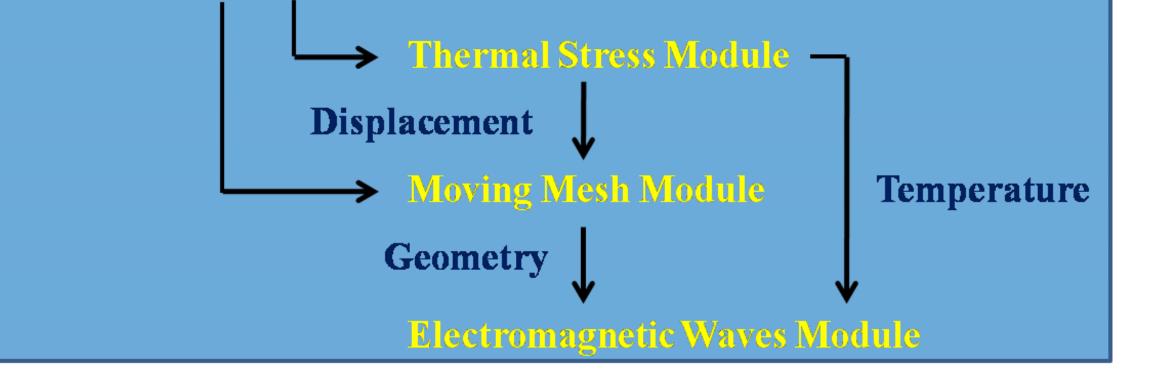
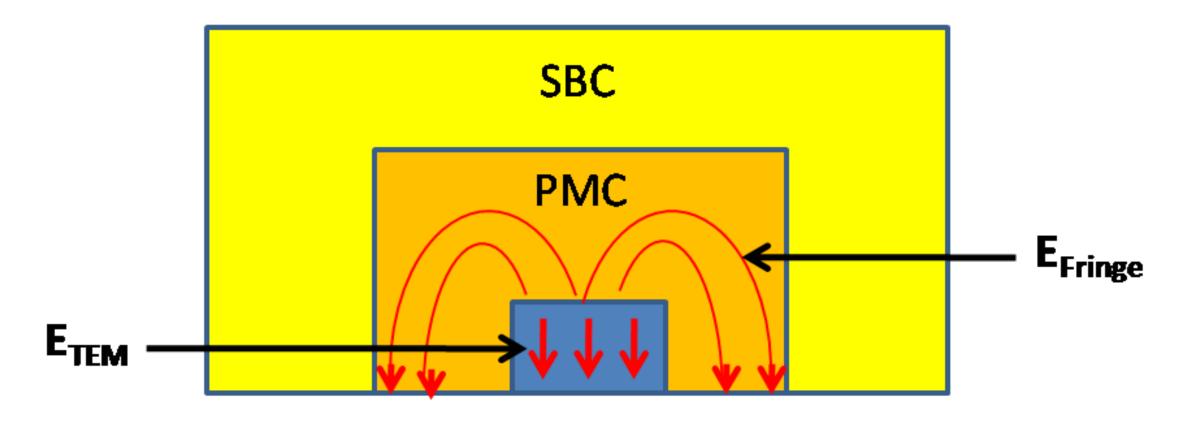
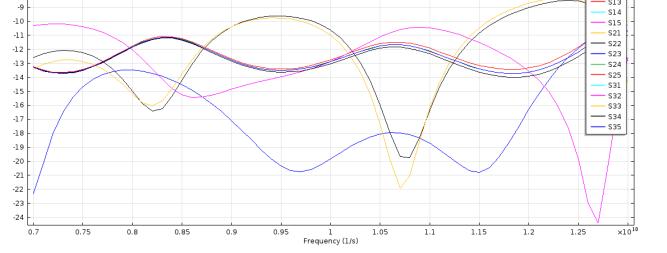


Figure 2. Computation Logical Diagram.

Fringe effects on the microstrip ports are considered by introducing a Perfect Magnetic Conductor (PMC) on a peripheral surface between the microstrip ports and the waveguide back open face, assigned to a Scattering Boundary Condition (SBC).





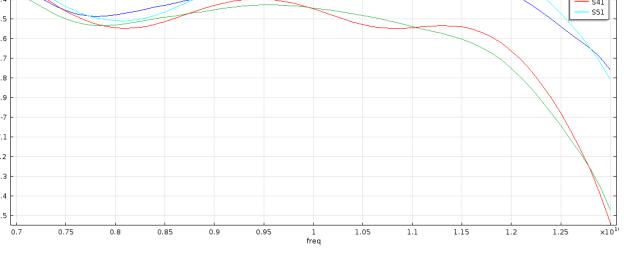


Figure 8. S-Parameter.

Figure 9. Transmission.

Conclusions: A complete Multiphysics model of the proposed SPC has been implemented and it has allowed to choose proper materials.

References:

 Ha Trong Than et al. "Design and Performance of a 600-W C-Band Amplifier Using Spatially Combined GaAs FETs for Satellite Communications", *IEEE Journal Of Solid-State Circuits*, VOL. 47, NO. 10, 2012.
 B.Bhat, S.K.Koul: "Analysis, Design and Optimization of Fin Lines", Artech House, 1987.
 George E. Ponchak, Alan N. Downey: "A New Model for Broadband Waveguide to Microstrip Transition Design", *NASA Technical Memorandum 88905*, Lewis Research Center Cleveland, Ohio, DEC.1986.

Figure 3. Fringe effects representation.

Results: By imposing a power dissipation of 20 W for each of the 4 GaAs active devices, (considering their conversion efficiency), the

- 4. COMSOL Structural Mechanics Module User's Guide Version: 4.3.
- 5. COMSOL Multiphysics User's Guide, Version: 4.3.
 6. COMSOL RF Module User's Guide Version: 4.3.

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